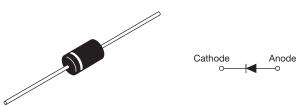
Vishay Semiconductors

Schottky Rectifier, 1.1 A



www.vishay.com

DO-204AL

PRODUCT SUMMARY					
Package	DO-204AL (DO-41)				
I _{F(AV)}	1.1 A				
V _R	90 V, 100 V				
V _F at I _F	See Electrical table				
I _{RM}	1.0 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	1.0 mJ				

FEATURES

- · Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

DESCRIPTION

The VS-11DQ... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UN						
I _{F(AV)}	Rectangular waveform	1.1	А					
V _{RRM}		90/100	V					
I _{FSM}	t _p = 5 μs sine	85	А					
V _F	1 Apk, T _J = 25 °C	0.85	V					
TJ	Range	- 40 to 150	°C					

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-11DQ09	VS-11DQ09-M3	VS-11DQ10	VS-11DQ10-M3	UNITS	
Maximum DC reverse voltage	V _R	90	90	100	100	V	
Maximum working peak reverse voltage	V _{RWM}	90	90	100	100	v	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T_{C} = 75 °C, rectangular waveform		1.1			
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	85	А		
See fig. 6	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	14			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 8 mH		1.0	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.5	А		

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1



COMPLIANT

HALOGEN

FREE

Available

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			
	V _{FM} ⁽¹⁾	1 A	T ₁ = 25 °C	0.85	V	
Maximum forward voltage drop See fig. 1		2 A	1j=25 0	0.96		
		1 A	T.I = 125 °C	0.68		
		2 A	$1_{\rm J} = 125$ C	0.78		
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.5	mA	
See fig. 2		T _J = 125 °C	V _R = naleu V _R	1.0	ША	
Typical junction capacitance	C _T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		35	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 8.0			nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/μs			V/µs	

Note

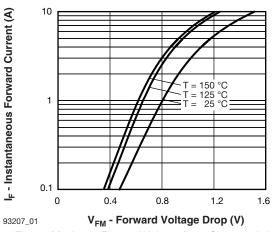
 $^{(1)}\,$ Pulse width < 300 $\mu s,\,duty\,cycle$ < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C		
Maximum thermal resistance, junction to ambient	R _{thJA}	R _{thJA} DC operation Without cooling fin		°C/W		
Typical thermal resistance, junction to lead	R _{thJL}	DC operation See fig. 4	81	0/11		
Approvimate weight			0.33	g		
Approximate weight			0.012	oz.		
Marking device			11DQ09			
		Case style DO-204AL (DO-41)	11DQ10			

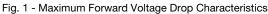
Note

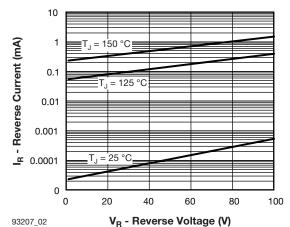
 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

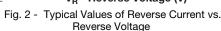
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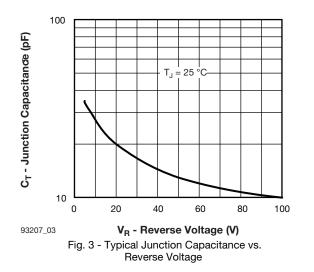


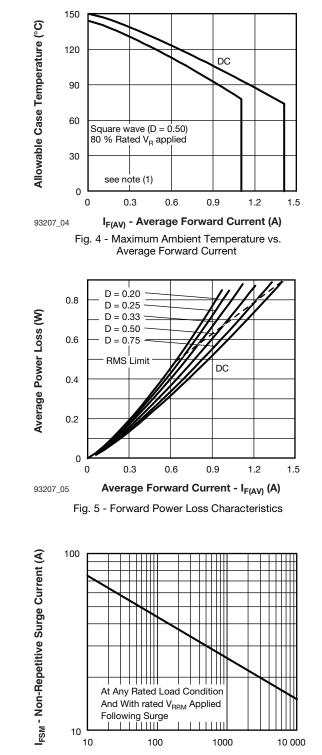
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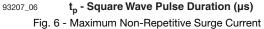












Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} \times I_{R} (1 - D); I_{R} at V_{R1} = 80 \% rated V_{R1} \times I_{R1} = 10 \% rated V_{R1} \times I_{R1} \times$

Revision: 21-Sep-11

3

Document Number: 93207

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ORDERING INFORMATION TABLE

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								_
Device code	VS-	11	D	Q	10	TR	-M3	
	1	2	3	4	5	6	7	
	1 -	Vish	nay Sem	niconduc	tors pro	duct		
	2 -	11 =	= 1.1 A (axial an	d small	packag	es - cur	rrent is x 10)
	3 -	D =	DO-41	package)			
	4 -	Q =	Schottk	xy Q se	ries		Г	
	5 -	10 =	Voltag	e ratings	s ———			09 = 90 V 10 = 100 V
	6 -	TR	= Tape	and reel	packag	е	L	
		Nor	ie = Bull	k packa	ge			
	7 -	Env	ironmer	ntal digit				
		• No	one = Le	ead (Pb)	-free an	d RoHS	6 compl	liant
		- N	0 - 11-1	-	Dell	• • • • • • •	1	and the survey line of the second line

• -M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-11DQ09	1000	1000	Bulk		
VS-11DQ09TR	5000	5000	Tape and reel		
VS-11DQ09-M3	1000	1000	Bulk		
VS-11DQ09TR-M3	5000	5000	Tape and reel		
VS-11DQ10	1000	1000	Bulk		
VS-11DQ10TR	5000	5000	Tape and reel		
VS-11DQ10-M3	1000	1000	Bulk		
VS-11DQ10TR-M3	5000	5000	Tape and reel		

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95241				
Part marking information	www.vishay.com/doc?95304				
Packaging information	www.vishay.com/doc?95338				

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27.0 (1.06) MIN. (2 places)

1.27 (0.050) MAX.

Flash (2 places)

2.70 (0.106)

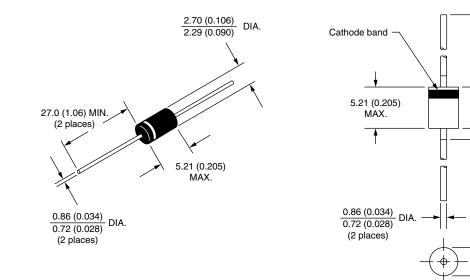
2.29 (0.090)

DIA.



Axial DO-204AL (DO-41)

DIMENSIONS in millimeters (inches)





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